Supplementary information

Laser co-ablation of bismuth antimony telluride and diamondlike carbon nanocomposites for enhanced thermoelectric performance

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Scielled ARD peaks			
BST	(015) (0015)		
Deposition temperature	Grain size (nm)	Grain size (nm)	
400 °C	47.8	74.9	
500 °C	117.8	63.2	
600 °C	134.9	80.6	
BST:DLC	(015)	(0015)	
Deposition temperature	Grain size (nm)	Grain size (nm)	
400 °C	43.3	21.5	
500 °C	51.0	28.3	
600 °C	89.9	47.5	

Table S1 Estimated grain sizes using full width at half maximum (FWHM) of some selected XRD peaks

Table S2 Energy dispersive X-ray spectroscopy (EDX) characterization

BST:DLC -	at %			
	Bi	Sb	Te	С
400 °C	5.0	14.7	28.5	51.7
500 °C	5.0	15.5	28.9	50.5
600 °C	4.7	19.0	31.6	44.7

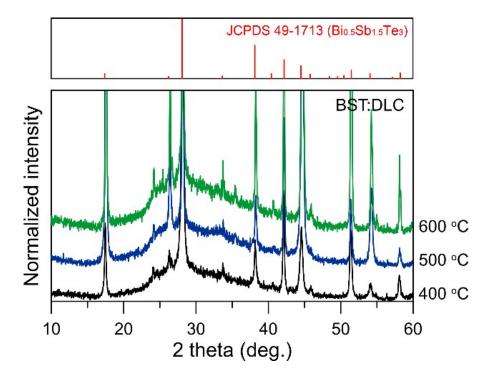


Fig. S1 The XRD patterns clearly displaying the extremely broadening diffraction peak around $2\theta=24^{\circ}-26^{\circ}$ which can be indexed as (002) of DLC (carbon).

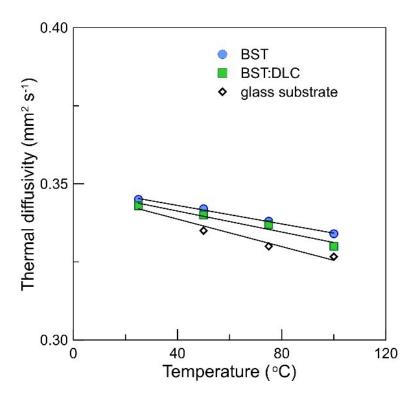


Fig. S2 Temperature dependent thermal diffusivities obtained from the BST and BST:DLC films deposited at 500 °C on glass substrates.